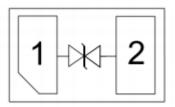


Description

The JS45B1GD20-2 is a Bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The JS45B1GD20-2 complies with the IEC 61000-4-2 (ESD) standard with $\pm 30 \rm kV$ air and $\pm 30 \rm kV$ contact discharge.It is assembled into an ultra-small 1.0x0.6x0.5mm DFN package. The small size and high ESD surge protection make JS45B1GD20-2 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Circuit Diagram



Circuit and Pin Schematic

Marking Diagram



Transparent top view

45:Device Marking Code

Features

- * 600W peak pulse power (8/20µs)
- * Low leakage: uA level
- Operating voltage: 4.5V
- * Ultra low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 40A (8/20μs)
- * Package: DFN1006-2
- * RoHS Compliant

Applications

- Fast-charge battery chargers
- * Power management system
- * Cellular Handsets and Accessories
- * Personal Digital Assistants
- * Notebooks and Handhelds
- * Portable Instrumentation
- * Digital Cameras

Ordering Information

Part Number	Packaging	Reel Size
JS45B1GD20-2	10000/Tape & Reel	7 inch



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

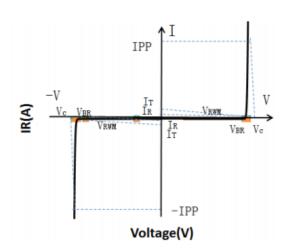
Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20μs)	Ppk	600	W	
Peak Pulse Current (8/20μs)	IPP	40	A	
ESD per IEC 61000-4-2 (Air)	VECD	±30	1-17	
ESD per IEC 61000-4-2 (Contact)	VESD	±30	kV	
Operating Temperature Range	TJ	-55to +125	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse Working Voltage	Vrwm				4.5	V
Breakdown Voltage	VBR	$I_T = 1 \text{mA}$	5	6	7	V
Reverse Leakage Current	I_R	$V_{RWM} = 4.5V$			0.5	μΑ
Clamping Voltage	Vc	IPP = $1A (8 \times 20 \mu s \text{ pulse})$			6	V
Clamping Voltage	Vc	$I_{PP} = 40A (8 \times 20 \mu s \text{ pulse})$			15	V
Junction Capacitance	Сл	VR = 0V, f = 1MHz		220	250	pF

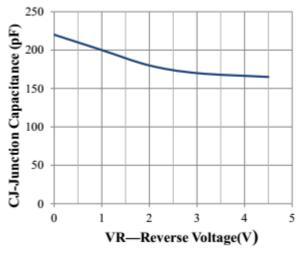
Portion Electronics Parameter

Symbol	Parameter		
IT	Test Current		
Ірр	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @Ic		

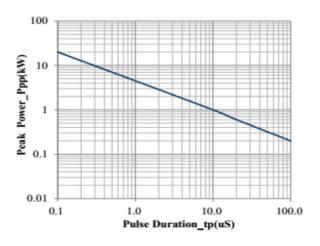




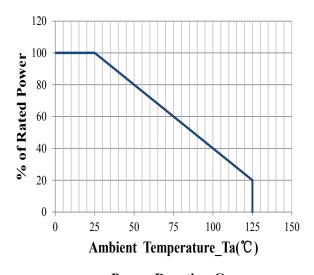
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



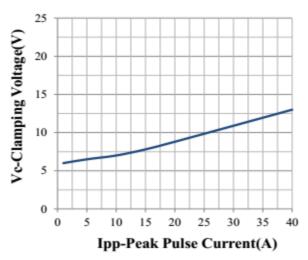
Junction Capacitance vs. Reverse Voltage



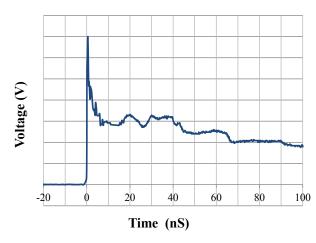
Peak Pulse Power vs. Pulse Time



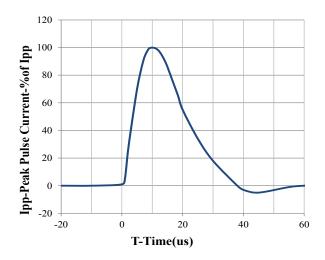
Power Derating Curve



Clamping Voltage vs. Peak Pulse Current



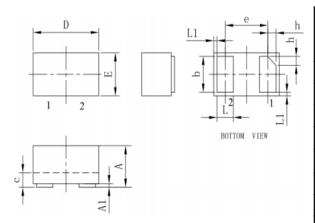
IEC61000-4-2 Pulse Waveform



8 X 20us Pulse Waveform

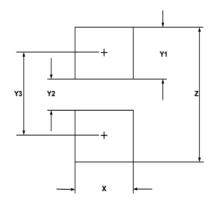


DFN1006-2 Package Outline Drawing (Dimensions in millimeters)



	DIMENSIONS					
	MI	ILLIMETERS		INCHES		
SYM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
С	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
е	0.65 BSC		(0.026 BS0		
Е	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.05REF		0.002REF			
h	0.07	0.12 0.17		0.003	0.005	0.007

Suggested Land Pattern



	DIMENSIONS		
SYM	MILLIMETERS	INCHES	
Х	0.60	0.024	
Y1	0.50	0.020	
Y2	0.30	0.012	
Y3	0.80	0.032	
Z	1.30	0.052	

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